

# TPS3809xxx-Q1 3-Pin Supply Voltage Supervisors

#### 1 Features

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
  - Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level 2
  - Device CDM ESD Classification Level C5
- 3-Pin SOT-23 Package
- Supply Current of 9 µA (Typical)
- Precision-Supply Voltage Monitor 2.5 V, 3 V, 3.3 V,
- Power-On Reset Generator With Fixed Delay Time of 200 ms
- Pin-For-Pin Compatible With MAX 809

## 2 Applications

- **Automotive Camera Systems**
- **Telematics**
- **Automotive Cluster**
- **Engine Controls**
- Surround View Systems

# 3 Description

The TPS3809 family of supervisory circuits provides circuit initialization and timing supervision, primarily for DSPs and processor-based systems. The newer TLV809E device is an alternative with the same pins, functions and electrical parameters.

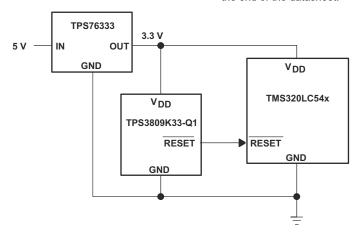
During power-on, RESET is asserted when the supply voltage VDD becomes higher than 1.1 V. Thereafter, the supervisory circuit monitors V<sub>DD</sub> and keeps RESET active as long as V<sub>DD</sub> remains below the threshold voltage VIT. An internal timer delays the return of the output to the inactive state (high) to ensure proper system reset. The delay time,  $t_{d(tvp)}$  = 200 ms, starts after V<sub>DD</sub> has risen above the threshold voltage V<sub>IT</sub>. When the supply voltage drops below the threshold voltage V<sub>IT</sub>, the output becomes active (low) again. No external components are required. All the devices of this family have a fixed sense-threshold voltage V<sub>IT</sub> set by an internal voltage divider.

The product spectrum is designed for supply voltages of 2.5 V, 3 V, 3.3 V, and 5 V. The circuits are available in a 3-pin SOT-23. The TPS3809xxx-Q1 devices are characterized for operation over a temperature range of -40°C to 125°C, and are qualified in accordance with AEC-Q100 stress test qualification for integrated circuits.

#### Device Information (1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
TPS3809xxx-Q1	SOT-23 (3)	2.90 mm × 1.60 mm		

For all available packages, see the orderable addendum at the end of the datasheet.



**Typical Application** 



## **Table of Contents**

nctional Block Diagram	8 9 9 9
ature Description	8 9 9 9
vice Functional Modes	9 9 9
ation and Implementationlication Informationical Applicationr Supply Recommendations	9 9 9
olication Informationical Applicationr Supply Recommendations	9 9 11
ical Applicationr Supply Recommendations	9 11
Supply Recommendations	11
<b>\_</b>	. 12
	. 13
	ayout Guidelines ayout Example.  e and Documentation Support

# **4 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision B (March 2016) to Revision C (December 2020)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Added new sentence regarding the new TLV809E to the Description section	1
•	Renamed Device Comparison modified device option table and added comparison table	3
•	Changed VDD from 7 to 6.5 in Absolute Maximum Ratings	4
•	Changed V <sub>OL</sub> @ 500µA from 0.2 to 0.3 in <i>Electrical Characteristics</i>	5
•	Changed t <sub>w</sub> pulse duration from 3 to 10µs in <i>Timing Requirements</i>	5
•	Changed t <sub>PHL</sub> from 1 to 10µs in Switching Characteristics	5
	Deleted figure for Minimum Pulse Duration At V <sub>DD</sub> in Typical Characteristics	
C	hanges from Revision A (December 2002) to Revision B (February 2016)	Page
•	Added AEC-Q100 Qualified information in bullets	1
•	Changed Applications list items	1
	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	
•	Changed device part numbers by adding -Q1 to them throughout document	



# **5 Device Comparison**

**Table 5-1. Device Threshold Options** 

<b>-</b>
THRESHOLD VOLTAGE
2.25 V
2.64 V
2.93 V
4.55 V

**Table 5-2. Device Family Comparison** 

	•
DEVICE	FUNCTION
TLV803	Open-Drain, RESET Output
TLV809	Push-Pull, RESET Output
TLV810	Push-Pull, RESET Output

# **6 Pin Configuration and Functions**

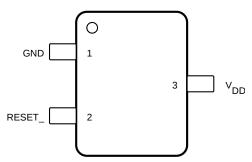


Figure 6-1. DBV Package 3-Pin SOT-23 Top View

#### **6.1 Pin Functions**

PIN NAME NO.		I/O	DESCRIPTION		
					GND
RESET	2	0	Reset output		
$V_{DD}$	3	I	Supply voltage and supervising input		

# 7 Specifications

# 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	MIN	MAX	UNIT
Supply voltage, V <sub>DD</sub> <sup>(2)</sup>		6.5	V
All other pins <sup>(2)</sup>	-0.3	6.5	V
Maximum low output current, I <sub>OL</sub>		5	mA
Maximum high output current, I <sub>OH</sub>		<b>-</b> 5	mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> <0 or V <sub>I</sub> >V <sub>DD</sub> )	-20	20	mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> <0 or V <sub>O</sub> >V <sub>DD</sub> )	-20	20	mA
Continuous total power dissipation			
Operating free-air temperature range, T <sub>A</sub>	-40	125	°C
Storage temperature, T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 7.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human-body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-011	±750	<b>'</b>

<sup>(1)</sup> AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

# 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
$V_{DD}$	Supply voltage	2	6	V
T <sub>A</sub>	Operating free-air temperature	-40	125	°C

#### 7.4 Thermal Information

		TPS3809xxx-Q1		
	THERMAL METRIC(1)	DBV (SOT-23)	UNIT	
		3 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	232.5	°C/W	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	187.6	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	104.1	°C/W	
ΨЈТ	Junction-to-top characterization parameter	40.5	°C/W	
ΨЈВ	Junction-to-board characterization parameter	104.4	°C/W	
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

<sup>(2)</sup> All voltage values are with respect to GND. For reliable operation the device should not be operated at 6.5 V for more than t = 1000 h continuously.



#### 7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
	High-level output voltage		$V_{DD}$ = 2.5 V to 6 V, $I_{OH}$ = -500 $\mu A$		V <sub>DD</sub> - 0.2			
\ <u>\</u>			$V_{DD} = 3.3 \text{ V}, I_{OH} = -2 \mu A$		V <sub>DD</sub> - 0.4			<sub>v</sub>
V <sub>OH</sub>			V <sub>DD</sub> = 6 V, I <sub>OH</sub> = -4 mA	$T_A = -40^{\circ}\text{C to } +25^{\circ}\text{C}$	V <sub>DD</sub> - 0.4			, v
			VDD - 0 V, IOH4 IIIA	T <sub>A</sub> = 125°C	V <sub>DD</sub> – 0.5			
			$V_{DD} = 2 \text{ V to 6 V, } I_{OL} = 5$	00 μA			0.3	
V <sub>OL</sub>	Low-level output voltage		$V_{DD} = 3.3 \text{ V}, I_{OL} = 2 \text{ mA}$				0.4	V
			V <sub>DD</sub> = 6 V, I <sub>OL</sub> = 4 mA				0.4	.4
	Power-up reset voltage <sup>(1)</sup>		V <sub>DD</sub> ≥ 1.1 V, I <sub>OL</sub> = 50 μA				0.2	V
	Negative-going input threshold voltage <sup>(2)</sup>	TPS3809J25-Q1			2.20	2.25	2.30	
		TPS3809L30-Q1	T <sub>A</sub> = -40°C to +125°C		2.58	2.64	2.7	v
V <sub>IT</sub> -		TPS3809K33-Q1			2.87	2.93	2.99	
		TPS3809I50-Q1	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$		4.45	4.55	4.65	
		1753609150-0	1F33609130-Q1	$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		4.4	4.55	4.65
		TPS3809J25-Q1				30		
.,	Lhistoropia	TPS3809L30-Q1				35		mV
V <sub>hys</sub>	Hysteresis	TPS3809K33-Q1				40		IIIV
		TPS3809I50-Q1				60		
	Supply current		V <sub>DD</sub> = 2 V, Output uncon	nected		9	15	
I <sub>DD</sub>	Supply current		V <sub>DD</sub> = 6 V, Output uncon	nected		20	30	30 µA
Ci	Input capacitance	ve V <sub>I</sub> = 0 V to V <sub>DD</sub>				5		pF

<sup>(1)</sup> The lowest supply voltage at which  $\overline{RESET}$  becomes active.  $t_r$ ,  $V_{DD} \ge 15 \mu s/V$ .

# 7.6 Timing Requirements

 $R_L = 1 M\Omega, C_L = 50 pF, T_A = 25^{\circ}C$ 

			MIN	NOM	MAX	UNIT
t <sub>w</sub>	Pulse width at $V_{DD}$	$V_{DD} = V_{IT-} + 0.2 \text{ V}, \text{VDD} = V_{IT-} - 0.2 \text{ V}$	10			μs

## 7.7 Switching Characteristics

 $R_L$  = 1 M $\Omega$ ,  $C_L$  = 50 pF,  $T_A$  = 25°C

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>d</sub>	Delay time		V <sub>DD</sub> ≥ V <sub>IT</sub> + 0.2 V, See timing diagram, Section 7.8	120	200	280	ms
t <sub>PHL</sub>	Propagation (delay) time, high-to-low-level output	V <sub>DD</sub> to RESET delay	V <sub>IL</sub> = V <sub>IT</sub> - 0.2 V, V <sub>IH</sub> = V <sub>IT</sub> +0.2 V		10		μs

<sup>(2)</sup> To ensure best stability of the threshold voltage, a bypass capacitor (0.1 µF, ceramic) should be placed near the supply terminals.



# 7.8 Timing Diagrams

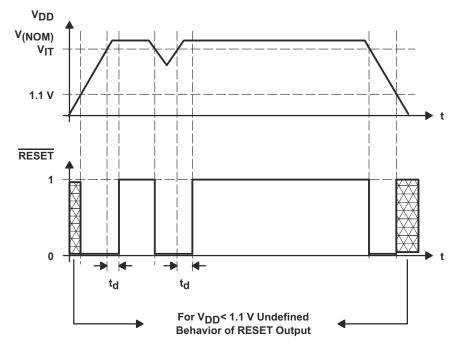


Figure 7-1. Timing Diagram



## 7.9 Typical Characteristics

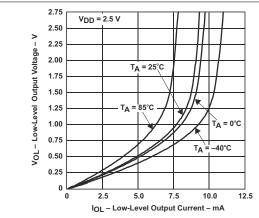


Figure 7-2. Low-Level Output Voltage vs Low-Level Output Current

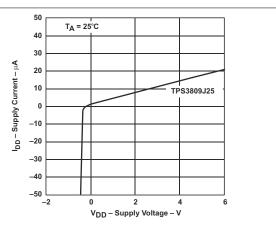


Figure 7-3. Supply Current vs Supply Voltage

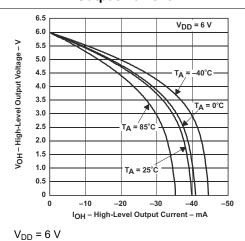
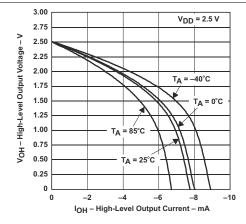
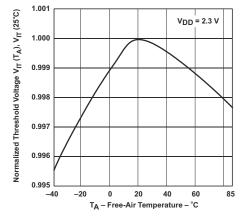


Figure 7-4. High-Level Output Voltage vs High-Level Output Current



 $V_{DD} = 2.5 \text{ V}$ 

Figure 7-5. High-Level Output Voltage vs High-Level Output Current



 $V_{DD}$  = 2.3 V

Figure 7-6. Normalized Input Threshold Voltage vs Free-Air Temperature at  $V_{DD}$ 

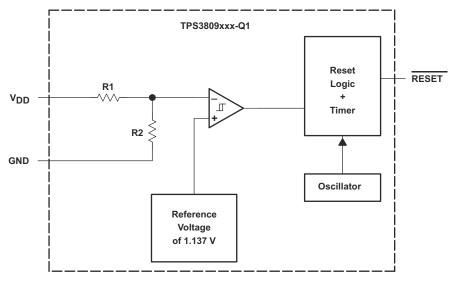


### 8 Detailed Description

#### 8.1 Overview

The TPS3809xxx-Q1 device is a low-current supervisory circuit for monitoring system voltages above 2 V. The device asserts an active-low RESET signal when VDD drops below a preset threshold. The RESET output remains low until VDD returns above its threshold. The device design is also to be relatively immune to short negative transients on the VDD pin.

### 8.2 Functional Block Diagram



#### 8.3 Feature Description

#### 8.3.1 V<sub>DD</sub> Monitoring

The  $V_{DD}$  pin provides a terminal at which a system voltage can be monitored. If the voltage on this pin drops below  $V_{IT}$ ,  $\overline{RESET}$  is asserted low. The comparator has a built-in hysteresis to ensure smooth  $\overline{RESET}$  assertions and deassertions. Refer to Section 5 to determine the  $V_{DD}$  voltage threshold for each device.

#### 8.4 Device Functional Modes

TPS3809xxx-Q1 monitors one supply using the  $V_{DD}$  pin. When  $V_{DD}$  is above the  $V_{IT}$  threshold for the device, RESET will be high. When  $V_{DD}$  is below the  $V_{IT}$  threshold for the device, RESET will be low.



## 9 Application and Implementation

#### **Note**

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

The TPS3809xxx-Q1 voltage supervisor device design asserts an active-low RESET signal when  $V_{DD}$  drops below a voltage threshold  $V_{IT}$ . The  $\overline{RESET}$  signal remains low until the voltage returns above its threshold. The typical application is with a processor or microcontroller, which needs to be reset when the supply rail drops below a specified tolerance.

### 9.2 Typical Application

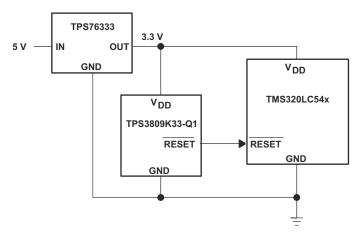


Figure 9-1. Typical Application Schematic

#### 9.2.1 Design Requirements

Each device has a fixed=voltage monitoring threshold, and the device should be chosen based on the voltage being monitored. Refer to *Section 5* to determine the VDD voltage threshold for each device. In this example, a 3.3V supply rail to a microcontroller will be monitored.

#### 9.2.2 Detailed Design Procedure

Because a 3.3-V supply rail needs to be monitored, TPS3809K33-Q1 should be used. This device has a 2.93-V threshold for reset. Connect the 3.3-V supply to the  $V_{DD}$  pin and the reset output of the supervisor to the reset pin of the microcontroller.



## 9.2.3 Application Curves

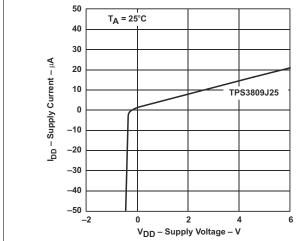


Figure 9-2. Supply Current vs Supply Voltage

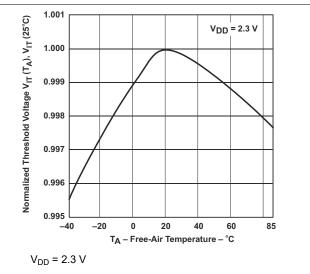


Figure 9-3. Normalized Input Threshold Voltage vs Free-Air Temperature at  $V_{\rm DD}$ 



# 10 Power Supply Recommendations

The TPS3809xxx-Q1 device design operates from an input supply from 2 V to 6 V. TI recommends placing a 0.1-  $\mu$ F capacitor near the V<sub>DD</sub> pin.



# 11 Layout

# 11.1 Layout Guidelines

TI recommends placing the 0.1- $\mu$ F decoupling capacitor close to the  $V_{DD}$  pin. The  $V_{DD}$  and GND traces should be able to carry 30  $\mu$ A without a significant drop in voltage.

# 11.2 Layout Example

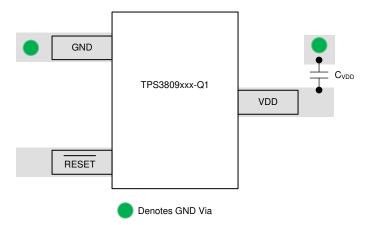


Figure 11-1. Layout Example



# 12 Device and Documentation Support

## 12.1 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 12.2 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 12.3 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.4 Glossary

**TI Glossary** 

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





10-Dec-2020

#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
2T09I50QDBVRG4Q	ACTIVE	SOT-23	DBV	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PDCQ	Samples
TPS3809I50QDBVRQ1	ACTIVE	SOT-23	DBV	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PDCQ	Samples
TPS3809K33QDBVRQ1	ACTIVE	SOT-23	DBV	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PDBQ	Samples
TPS3809L30QDBVRQ1	ACTIVE	SOT-23	DBV	3	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	PDAQ	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



# PACKAGE OPTION ADDENDUM

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TPS3809-Q1:

● Enhanced Product: TPS3809-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 19-Jan-2024

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
2T09I50QDBVRG4Q	SOT-23	DBV	3	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS3809I50QDBVRQ1	SOT-23	DBV	3	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS3809K33QDBVRQ1	SOT-23	DBV	3	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
TPS3809L30QDBVRQ1	SOT-23	DBV	3	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3



www.ti.com 19-Jan-2024

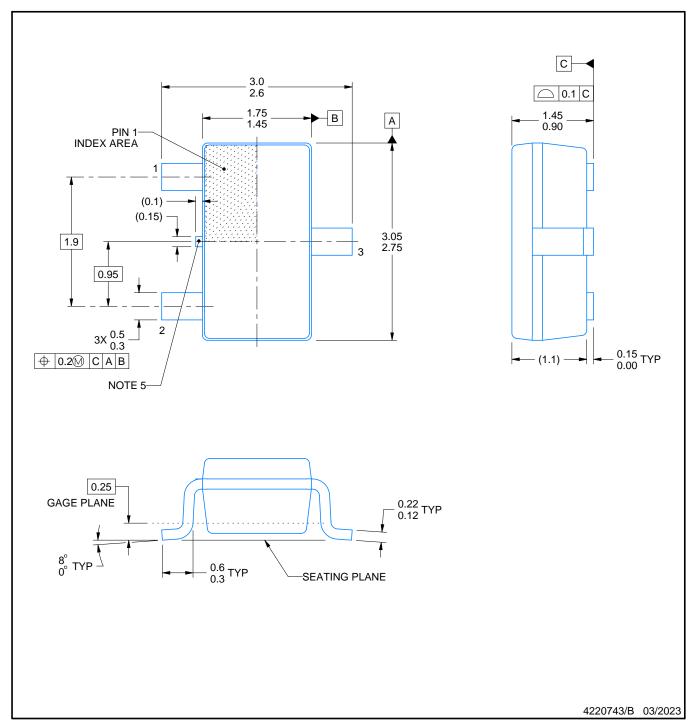


#### \*All dimensions are nominal

7 til dillionorio are memiliar							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
2T09l50QDBVRG4Q	SOT-23	DBV	3	3000	180.0	180.0	18.0
TPS3809I50QDBVRQ1	SOT-23	DBV	3	3000	180.0	180.0	18.0
TPS3809K33QDBVRQ1	SOT-23	DBV	3	3000	180.0	180.0	18.0
TPS3809L30QDBVRQ1	SOT-23	DBV	3	3000	180.0	180.0	18.0



SMALL OUTLINE TRANSISTOR



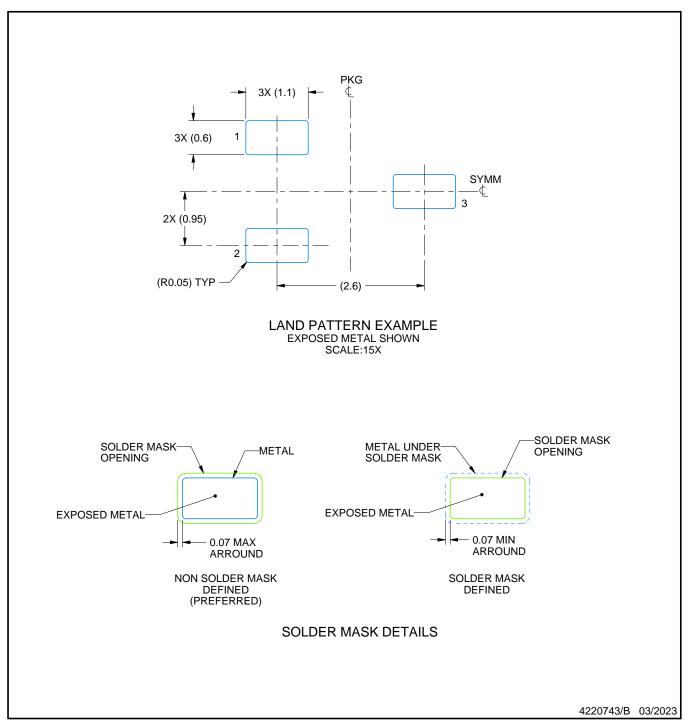
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



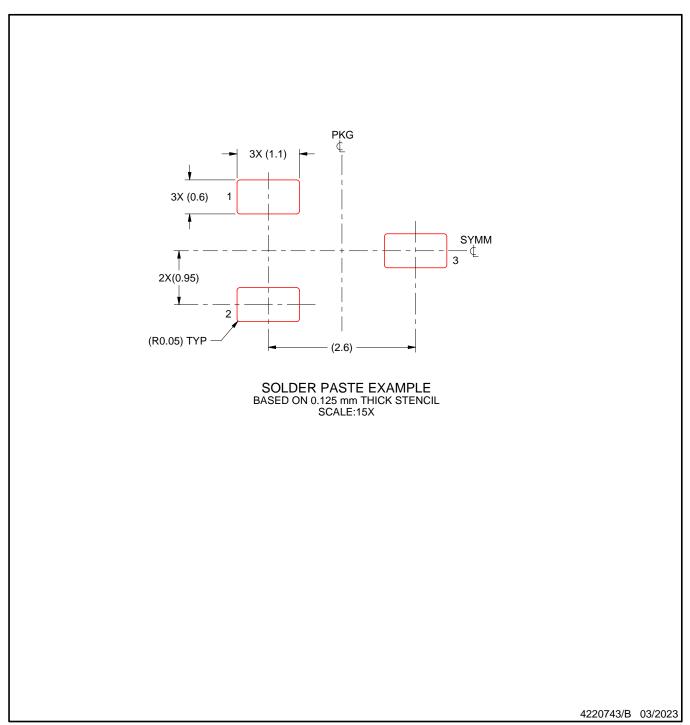
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated